

ENERGY METERING IC WITH PULSE OUTPUT

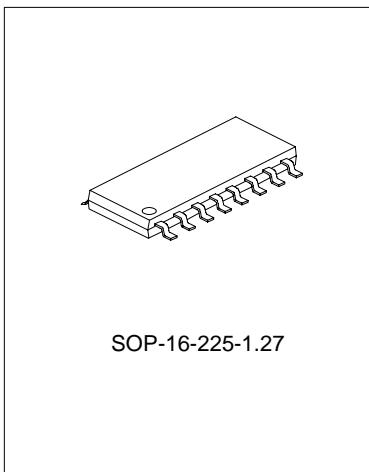
DESCRIPTION

The SC3333 is a high accuracy electrical energy measurement IC that can provide superior stability and accuracy over extremes in environmental conditions and over time. The SC3333 does not exhibit any creep when there is no load.

The SC3333 supplies average real power information on the low frequency outputs F1 and F2. These logic outputs may be used to directly drive an electromechanical counter or interface to an MCU. The CF logic output gives instantaneous real power information. This output is intended to be used for calibration purposes, or interfacing to an MCU.

The SC3333 includes a power supply monitoring circuit on the VDD supply pin. If the supply falls below 4V, the SC3333 will be reset and F1, F2 will be set to logic high, CF will be set to logic low at the same time.

The SC3333 provides synchronous frequency output for auto-reading meter system. The CF logic output is synchronous with the F1 and F2 logic output to ensure the show value of the meter is consonant with the real value.

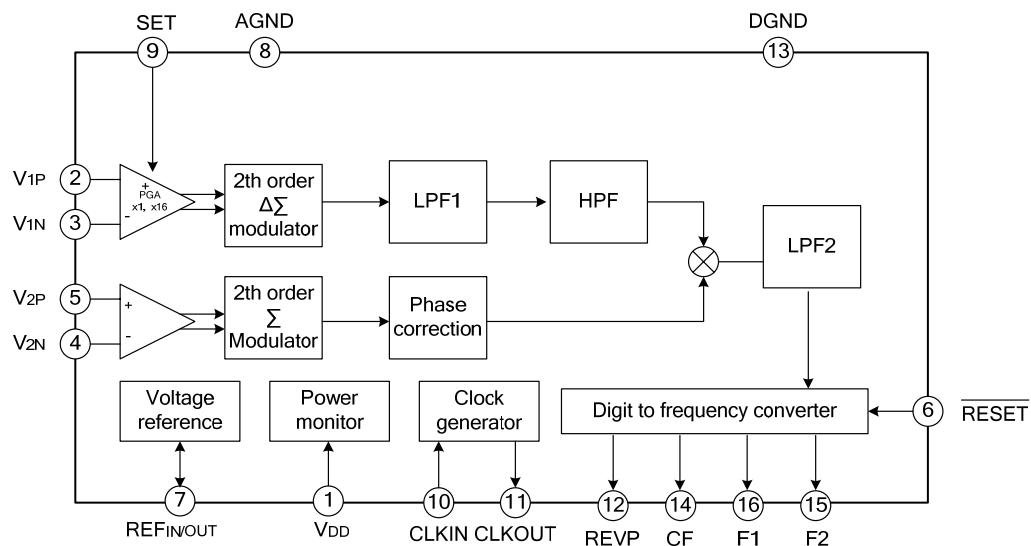


ORDERING INFORMATION

Device	Package
SC3333	SOP-16-225-1.27

FEATURES

- * Single 5V supply, low power.
- * On-chip power supply monitoring.
- * On-chip reference with external overdrive capability.
- * Supplies average real power on the frequency outputs F1 and F2, which can drive for electromechanical counters directly.
- * The high frequency output CF is intended for calibration and supplies instantaneous real power.
- * Less than 0.1% error over a dynamic range of 500 to 1.
- * On-chip creep protection (No load threshold).
- * The logic output REVP can be used to indicate a potential miswiring or negative power.
- * A PGA in the current channel makes flexible to select the shunt and burden resistance.

BLOCK DIAGRAM

ABSOLUTE MAXIMUM RATING ($T_{amb}=25^{\circ}\text{C}$, unless otherwise specified)

Characteristics	Symbol	Ratings	Unit
VDD to AGND/DGND	VDD	-0.3 ~ +7	V
Analog Input Voltage to AGND V1P, V1N, V2P and V2N	AVIN	-6 ~ +6	V
Reference Input voltage to AGND	VREF	-0.3 ~ VDD+0.3	V
Digital Input Voltage to DGND	DVIN	-0.3 ~ VDD+0.3	V
Digital Output Voltage to DGND	DVOUT	-0.3 ~ VDD+0.3	V
Power Dissipation	PD	450	mW
Operating Temperature Range	TOPR	-40~ +85	°C
Storage Temperature	TSTG	-65~ +150	°C
Junction Temperature	TJ	+150	°C

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^{\circ}\text{C}$, unless otherwise specified)

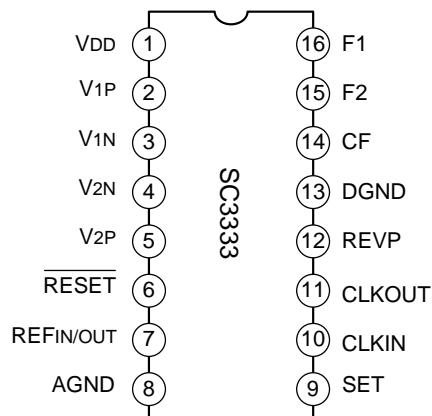
Characteristics	Symbol	Test conditions	Min.	Typ.	Max.	Unit
Power Supply						
Power Supply	VDD	5V±5%	4.75	--	5.25	V
Analog Input Current	AIDD	(2mA) TYP.	--	--	3	mA
Digital Input Current	DIIDD	(1.5mA) TYP.	--	--	2.5	
ACCURACY						
Measurement	Gain=1	EM	Over a dynamic range 500 to 1		--	0.1
Error ¹ on Channel 1	Gain=16		Over a dynamic range 500 to 1		--	0.1

(To be continued)

(Continued)

Characteristics	Symbol	Test conditions	Min.	Typ.	Max.	Unit	
Phase Error ¹ Between Channels	V1 Phase Lead 37°	EP	--	--	±0.1	°	
	V1 Phase Lag 60°						
Output Frequency Rejection (AC)	CFA	V1=100mV, V2=100mV, SET=0	--	0.01	--	%	
Output Frequency Rejection (DC)	CFD	V1=100mV, V2=100mV, VDD=5V±250mV	--	0.01	--	%	
ANALOG INPUTS							
Maximum Signal Levels	LEVS	V1P, VIN V2N and V2P to AGND	--	--	±1	V	
Input Impedance (DC)	IMIN	CLKIN=3.58MHz	400	--	--	kΩ	
Bandwidth (-3dB)	BW	CLKIN/256, CLKIN=3.58MHz	--	14	--	kHz	
ADC Offset Error ^{1,2}	EADC		--	--	15	mV	
Gain Error ¹	EG	V1=470mV, V2=660mV	--	±4	--	%	
Gain Error Match ¹	EGM	External 2.5V reference	--	±0.2	--	%	
REFERENCE INPUT							
REFIN/OUT Input Voltage Range	VINR	2.5V±8%	2.3	--	2.7	V	
Input Impedance	IMIN	--	3.7	--	--	kΩ	
Input Capacitance	CIN	--	--	--	10	pF	
ON-CHIP REFERENCE							
Reference Error	ER	Nominal 2.5V	--	--	200	mV	
Temperature Coefficient	TC		--	30	60	ppm/°C	
CLKIN							
Input Clock Frequency	CLKIN	Note all specifications for CLKIN of 3.58MHz	1	--	4	MHz	
LOGIC INPUTS³							
Input High Voltage	VINH	VDD=5V±5%	2.4	--	--	V	
Input Low Voltage	VINL	VDD=5V±5%	--	--	0.8	V	
Input Current	IIN	Typically 10nA, VIN=0V to VDD	--	--	±3	μA	
Input Capacitance	CIN		--	--	10	pF	
LOGIC OUTPUTS³							
F1 and F2	Output High Voltage	VOH	ISOURCE=10mA, VDD=5V	4.5	--	--	V
	Output Low Voltage	VOL	ISINK=10mA, VDD=5V	--	--	0.5	V
CF and REVP	Output High Voltage	VOH	ISOURCE=5mA, VDD=5V	4	--	--	V
	Output Low Voltage	VOL	ISINK=5mA, VDD=5V	--	--	0.5	V

PIN CONFIGURATION



PIN DESCRIPTION

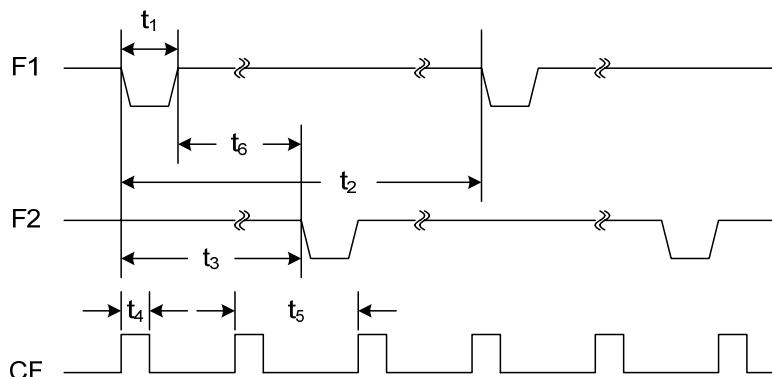
Pin No.	Symbol	Description
1	VDD	Power Supply.
2	V1P	Positive and Negative Inputs for Channel 1 (Current Channel). Channel 1 has a PGA and the gain selections are outlined in Table I. The maximum signal level at these pins is $\pm 1V$ with respect to AGND.
3	V1N	
4	V2N	Negative and Positive Inputs for Channel 2 (Voltage Channel). The maximum differential input voltage is $\pm 660mV$ for specified operation. The maximum signal level at these pins is $\pm 1V$ with respect to AGND.
5	V2P	
6	RESET	Reset Pin for the SC3333. A logic low is valid.
7	REFIN/OUT	Reference voltage input/output pin.
8	AGND	Analog ground.
9	SET	Channel 1 gain select pin. See table 1.
10	CLKIN	3.58MHZ crystal oscillator input pin.
11	CLKOUT	3.58MHZ crystal oscillator output pin.
12	REVPO	State indication pin. While negative power or a potential miswriting occurs, it will be set to logic high.
13	DGND	Digital ground.
14	CF	Calibration Frequency Logic Output..
15	F2	Low Frequency Logic Outputs. They can be used to directly drive a stepper motor or electromechanical impulse counter.
16	F1	

TIMING CHARACTERISTICS^{1,2}

(VDD=5V±5%, AGND=DGND=0V, On-chip Reference, CLKIN=3.58MHZ, TMIN to TMAX=-40°C~+85°C.)

Parameter	Test Condition	Test Data	Units
t1 ³	F1 and F2 Pulse-width	275	ms
t2	F1 and F2 Pulse Period.	TBD	sec
t3	Time Between F1 Falling Edge and F2 Falling Edge	1/2 t2	sec
t4 ³	CF Pulse-width	90	ms
t5	CF Pulse Period.	TBD	sec
t6	Minimum Time Between F1 and F2 Pulse	CLKIN/4	sec

- NOTE: 1. Sample tested during initial release and after any redesign or process change that may affect this parameter.
 2. See the following figure.
 3. The pulse-widths of F1, F2 and CF are not fixed for higher output frequencies.



Timing Diagram for Frequency outputs

Timing Diagram for Frequency Outputs shows a timing diagram for the various frequency outputs of the SC3333. The low frequency outputs, F1 and F2 can drive electromechanical counters and two phase stepper motors directly. As the figure shows, the F1 and F2 outputs provide two alternating low going pulses. The pulse width (t1) is set at 275ms and the time between the falling edges of F1 and F2 (t3) is approximately half the period of F1 (t2). If however the period of F1 and F2 falls below 550 ms (1.81Hz) the pulse width of F1 and F2 is set to half of their period. The frequency of F1 and F2 corresponds to the input voltages, and $F = (13.6 * V1 * V2 * G) / VREF^2$. The values of G can be set by consumers, and the selection of G please refer to the table I , V1 and V2 are the rms value of the two inputs, VREF is the voltage of reference, whose value is 2.5±0.2v when the internal bandgap reference of SC3333 is valid.

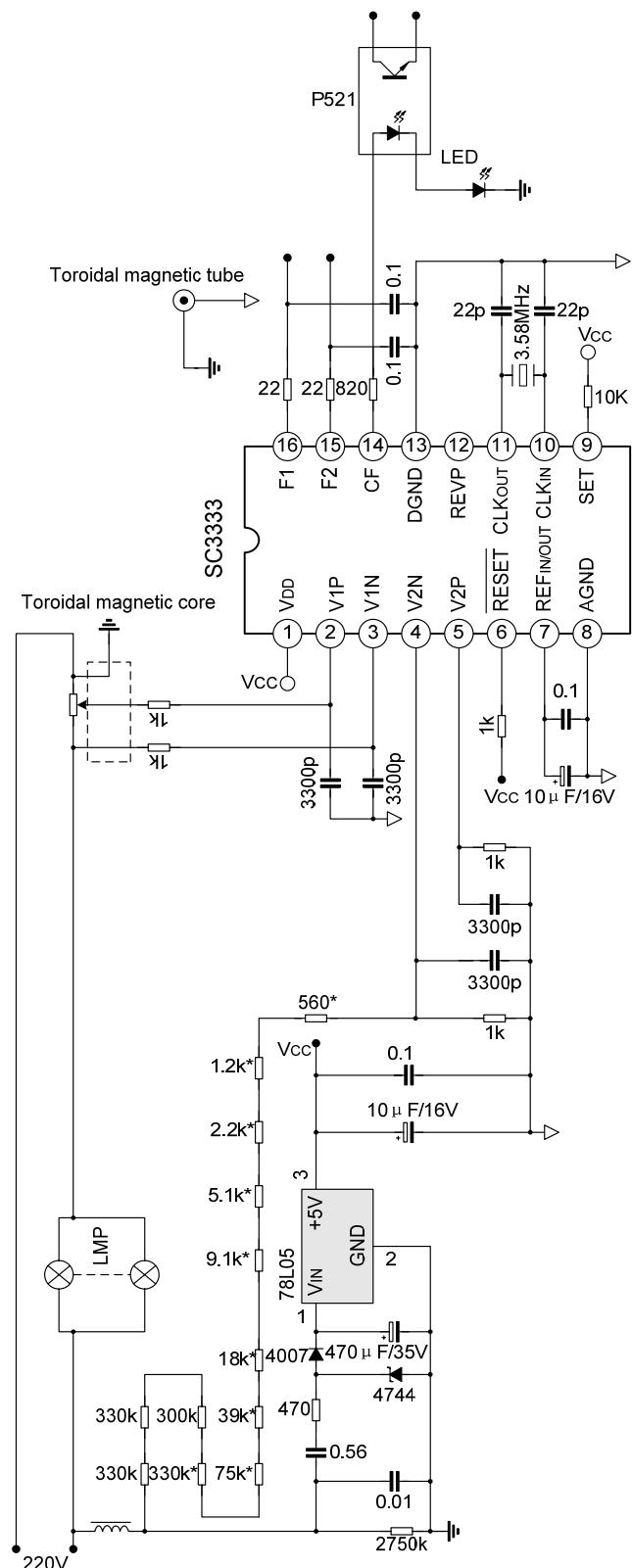
The high frequency output, CF is intended for calibration and supplies instantaneous real power. CF produces a 90ms wide active high pulse (t4) at a frequency proportional to active power. As in the case of F1 and F2, if the period of CF (t5) falls below 180ms, the CF pulse-width is set to half the period.

APPENDIX

Table I. gain selection for channel 1

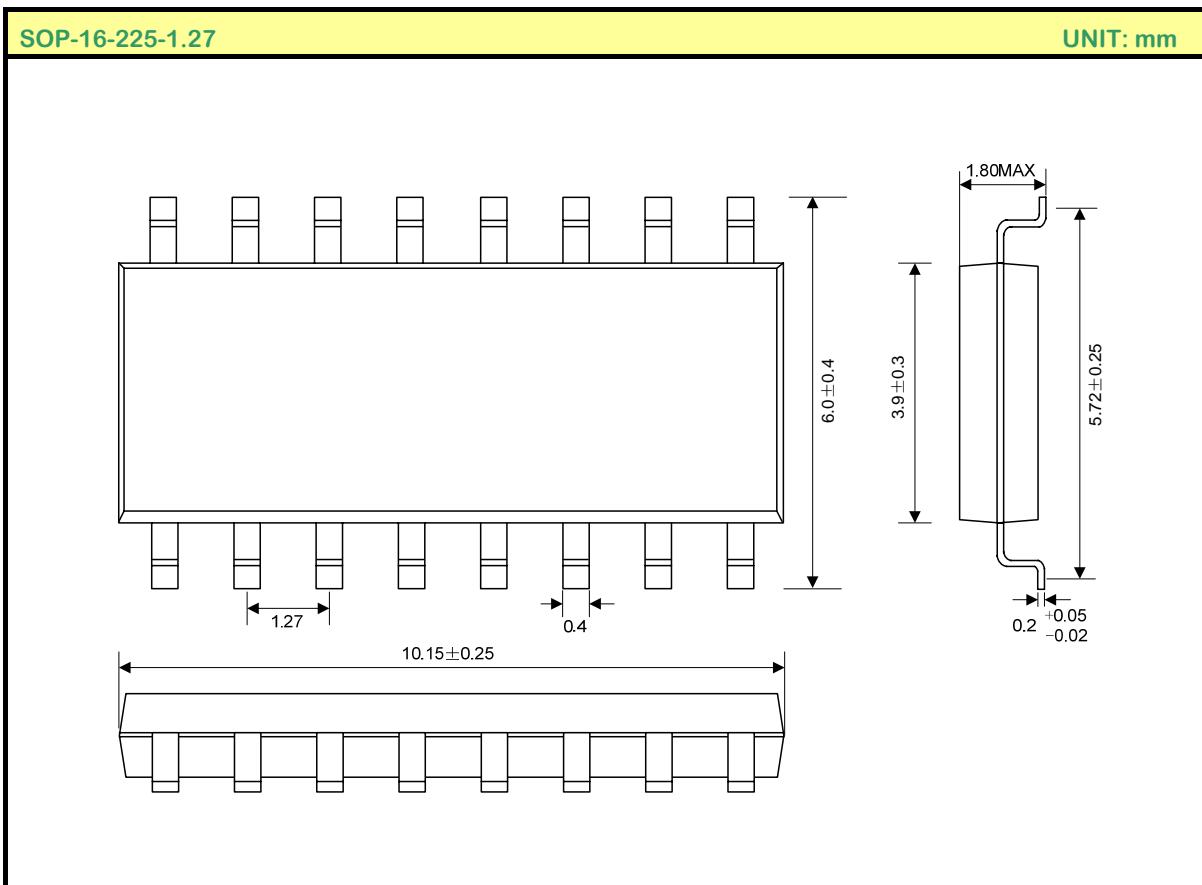
SET	Gain	Maximum Differential Signal
0	1	±470mV
1	16	±30mV

TYPICAL APPLICATION CIRCUIT



These resistors with * symbol used to adjust the precision of meters.

PACKAGE OUTLINE



HANDLING MOS DEVICES:

Electrostatic charges can exist in many things. All of our MOS devices are internally protected against electrostatic discharge but they can be damaged if the following precautions are not taken:

- Persons at a work bench should be earthed via a wrist strap.
- Equipment cases should be earthed.
- All tools used during assembly, including soldering tools and solder baths, must be earthed.
- MOS devices should be packed for dispatch in antistatic/conductive containers.